

## NSTRUMENTS 12500 TI Boulevard, MS 8640, Dallas, Texas 75243

# PCN# 20140319001B Add Cu as Alternative Wire Base Metal for Selected Device(s) on QFN, QFP and SOT-23 packages Change Notification / Sample Request

#### Dear Customer:

The purpose of this version B is to retract devices from this change notification. The retraction is for select devices that were inadvertently included and are not affected by this change. We apologize for any inconvenience this may have caused.

This is an announcement of a change to a device that is currently offered by Texas Instruments. The details of this change are on the following pages.

We request you acknowledge receipt of this notification within **30** days of the date of this notice. Lack of acknowledgement of this notice within 30 days constitutes acceptance of the change. If you require samples or additional data to support your evaluation, please request within 30 days.

The changes discussed within this PCN will not take effect any earlier than **90** days from the date of this notification, unless customer agreement has been reached on an earlier implementation of the change. This notification period is per TI's standard process.

This notice does not change the end-of-life status of any product. Should product affected be on a previously issued product withdrawal/discontinuance notice, this notification does not extend the life of that product or change the life time buy offering/discontinuance plan.

For questions regarding this notice, contact your local Field Sales Representative or the PCN Manager (PCN www\_admin\_team@list.ti.com).

Sincerely,

PCN Team SC Business Services

#### PCN# 20140319001B Attachment: 1

#### **Products Affected:**

According to our records, there are the affected device(s) that you have purchased within the past twenty-four (24) months. Technical details of this Product Change follow on the next page(s).

<b>PCN Number</b> : 20140319001			В					PCN Date:	09/01/2015
Title: Add Cu as Alternative Wire Base Metal for Selected Device(s) on QFN, QFP and SOT-23 packages									
Custo	Customer Contact: PCN Manager Dept: Quality Services								
Chang	је Туре:								
	Assembly Site			Design				Wafer Bump S	ite
	Assembly Proce	ess		Data Sh	neet			Wafer Bump M	laterial
$\boxtimes$	Assembly Mate	rials		Part nur	mber cha	ange		Wafer Bump P	rocess
	Mechanical Spe	ecification		Test Sit	е			Wafer Fab Site	9
	Packing/Shippi	ng/Labeling		Test Pro	ocess			Wafer Fab Mat	erials
								Wafer Fab Pro	cess
				PCN [	Details				
Descr	iption of Chan	ge:							
Texas device piece p	Revision B is to remove select devices in the Product Affected Section (with strikethrough) and highlighted in yellow. These devices were inadvertently added and not affected by this change. The other devices listed below with a strikethrough were retracted under revision A of PCN20140319001.  Texas Instruments is pleased to announce the qualification of Cu as an additional bond wire option for devices listed in "Product affected" section below. Devices will remain in current assembly facility and piece part changes as follows.  Group 1 Device: No other piece part change, Only Au to Cu wire  Group 2 Device: Changes Wire Composition and Wire Diameter  From  To  Wire  0.96 mil Au  0.80 mil Cu  Group 3 Device: Changes Mold Compound, Wire Composition and Wire Diameter								
	Mold Compoun		om , 450	0228		<b>To</b> 450413			
	Wire	0.60, 0.80	, 1.0	mil Au	0.80	), 1.0 mil (	Cu		
Reaso	on for Change:								
<ul> <li>Continuity of supply.</li> <li>1) To align with world technology trends and use wiring with enhanced mechanical and electrical properties</li> <li>2) Maximize flexibility within our Assembly/Test production sites.</li> <li>3) Cu is easier to obtain and stock</li> </ul>									
Anticipated impact on Fit, Form, Function, Quality or Reliability (positive / negative):									
None.									
Changes to product identification resulting from this PCN:									
None.									
1									

Product Affected: Groun	n 1 devices - No other nie	ece part change Only Au	to Cu wire			
Product Affected: Group 1 devices - No other piece part change, Only Au to Cu wire  TPS65633ARTER TPS65633RTET TPS65633RTET						
Product Affected: Group 2 devices - Changes Wire Composition and Wire Diameter						
	Product Affected: Group 3 devices - Changes Mold Compound, Wire Composition and Wire Diameter					
74AHC1G125DBVRE4	SN74AHC1G08DBVR	SN74LVC1G32DBVRG4	TS5A4594DBVRE4			
74AHC1G125DBVRG4	SN74AHC1G08DBVRE4	SN74LVC1G34DBVR	TS5A4594DBVRG4			
74AHC1G126DBVRE4	SN74AHC1G08DBVRG4	SN74LVC1G34DBVRE4	SN74AHC1G02DBVT			
74AHC1G126DBVRG4	SN74AHC1G125DBVR	SN74LVC1G34DBVRG4	SN74AHC1G86DBV6			
74AHC1GU04DBVRE4	SN74AHC1G126DBVR	SN74LVC1G66DBVR	SN74AHC1G86DBVT			
74AHC1GU04DBVRG4	SN74AHC1G86DBVR	SN74LVC1G66DBVRE4	SN74AHC1GU04DBVT			
74AHCT1G00DBVRE4	SN74AHC1G86DBVRE4	SN74LVC1G66DBVRG4	SN74AHCT1G00DBVT			
74AHCT1G00DBVRG4	SN74AHC1G86DBVRG4	SN74LVC1G79DBVR	SN74AHCT1G04DBVT			
74AHCT1G04DBVRE4	SN74AHC1GU04DBVR	SN74LVC1G79DBVRE4	SN74AHCT1G125DBVT			
74AHCT1G04DBVRG4	SN74AHCT1G00DBVR	SN74LVC1G79DBVRG4	SN74AHCT1G86DBV6			
74AHCT1G08DBVRE4	SN74AHCT1G04DBVR	SN74LVC1G80DBVR	SN74AHCT1G86DBVT			
74AHCT1G08DBVRG4	SN74AHCT1G08DBVR	SN74LVC1G80DBVRE4	SN74AUC1G04DBVR			
74AHCT1G125DBVRE4	SN74AHCT1G125DBVR	SN74LVC1G80DBVRG4	SN74AUC1G08DBVR			
74AHCT1G125DBVRG4	SN74AHCT1G126DBVR	SN74LVC1G86DBVR	SN74AUC1G125DBVR			
74AHCT1G126DBVRE4	SN74AHCT1G32DBVR	SN74LVC1G86DBVRE4	SN74AUC1G240DBVR			
74AHCT1G126DBVRG4	SN74AHCT1G86DBVR	SN74LVC1G86DBVRG4	SN74AUP1G04DBVT			
74AHCT1G32DBVRE4	SN74AUP1G04DBVR	SN74LVC1GU04DBVR	SN74AUP1G14DBVR			
74AHCT1G32DBVRG4	SN74AUP1G04DBVRE4	TL343IDBVR	SN74AUP1G32DBVR			
74AHCT1G86DBVRE4	SN74AUP1G04DBVRG4	TL343IDBVRE4	SN74AUP1G34DBVR			
74AHCT1G86DBVRG4	SN74AUP1G07DBVR	TL343IDBVRG4	SN74CBT1G384DBVR			
74AUP1G125DBVRE4	SN74AUP1G07DBVRE4	TL431ACDBVR	SN74CBT1G384DBVT			
74AUP1G125DBVRG4	SN74AUP1G07DBVRG4	TL431ACDBVRE4	SN74CBTD1G125DBVR			
74CBT1G125DBVRE4	SN74AUP1G125DBVR	TL431ACDBVRG4	SN74CBTD1G125DBVT			
74CBT1G125DBVRG4	SN74CBT1G125DBVR	TL431CDBVR	SN74CBTD1G384DBVR			
74CBTLV1G125DBVRE4	SN74CBTLV1G125DBVR	TL431CDBVRE4	SN74LVC1G02DBVT			
74CBTLV1G125DBVRG4	SN74LVC1G02DBVR	TL431CDBVRG4	SN74LVC1G06DBVT			
74LVC1G126DBVRE4	SN74LVC1G02DBVRE4	TL431IDBVR	SN74LVC1G07DBVT			
74LVC1G126DBVRG4	SN74LVC1G02DBVRG4	TL431IDBVRE4	SN74LVC1G132DBVT			
74LVC1G132DBVRE4	SN74LVC1G06DBVR	TL431IDBVRG4	SN74LVC1G14DBVT			
74LVC1G132DBVRG4	SN74LVC1G06DBVRE4	TLV431AIDBVR	SN74LVC1G240DBVT			
74LVC1G240DBVRE4	SN74LVC1G06DBVRG4	TLV431AIDBVRE4	SN74LVC1G32DBVT			
74LVC1G240DBVRG4	SN74LVC1G07DBVR	TLV431AIDBVRG4	SN74LVC1G34DBVT			
74LVC1GU04DBVRE4	SN74LVC1G07DBVRE4	TLV431CDBVR	SN74LVC1G66DBVT			
74LVC1GU04DBVRG4	SN74LVC1G07DBVRG4	TLV431CDBVRE4	SN74LVC1G79DBVT			
SN003166DBVR	SN74LVC1G126DBVR	TLV431CDBVRG4	SN74LVC1G80DBVT			
SN1003028DBVR	SN74LVC1G132DBVR	TLV431IDBVR	SN74LVC1G86DBVT			
SN74AHC1G02DBVR	SN74LVC1G14DBVR	TLV4311DBVRE4	SN74LVC1GU04DBVT			
SN74AHC1G02DBVRE4	SN74LVC1G14DBVRE4	TLV431IDBVRG4	TL431CDBVT			

SN74AHC1G02DBVRG4	SN74LVC1G14DBVRG4	TS5A3166DBVR	TS5A4595DBVR
SN74AHC1G04DBVR	SN74LVC1G240DBVR	TS5A3166DBVRE4	
SN74AHC1G04DBVRE4	SN74LVC1G32DBVR	TS5A3166DBVRG4	
SN74AHC1G04DBVRG4	SN74LVC1G32DBVRE4	TS5A4594DBVR	

# **Qualification Data: Group 1 Devices**

	annication Data				tion data		
	This qualification has been developed for the validation of this change. The qualification data validates that the proposed change meets the applicable released technical specifications.						
Qual Vehicle 1: TPA2017D2RTJ (MSL 2-260C)							
Package Construction Details							
Assembly Site:	TI-Clark		ad.	nd: 4208625			
-		Mold Compou					
# Pins-Designator, Family:	20-RTJ, QFN	Mount Compou		4207			
Lead frame (Finish, Base):	NiPdAu, Cu	Bond Wi	re:	0.96	Mil Dia.,	Cu	
Qualification: Plan							
Reliability Test	Conditions			San	nple Size/	'Fail	
Reliability Test	Conditions		Lo	t# 1	Lot# 2	Lot# 3	
**High Temp Storage Bake	170C (420 Hrs)		8	6/0	87/0	87/0	
**Autoclave	121C (240 Hrs)			7/0	87/0	87/0	
**T/C -65C/150C	-65C/+150C (500 Cy	vc)		7/0	77/0	77/0	
X-ray	(top side only)	10)		5/0	5/0	-	
Salt Atmosphere	24 Hours			2/0	22/0	22/0	
					22/0		
				Pass	Pass		
Moisture Sensitivity		2 260C peak +5/-0C)			12/0	12/0	
Moisture Sensitivity (level 2 @ 260C peak +5/-0C) 12/0 12/0 12/0 Notes **- Preconditioning sequence: Level 2-260C.							
Qual Vehicle 2: TPS2543QRTE (MSL 2-260C)							
	Package Constr	ruction Details					
Assembly Site:	TI-Clark	Mold Compou	ind: 4208625				
# Pins-Designator, Family:	16-RTE, QFN	Mount Compou	ınd: 4207768				
Lead frame (Finish, Base):	NiPdAu, Cu	Bond Wi	re: 2.0 Mil Dia., Cu				
Qualification:  Plan							
				San	nple Size/	'Fail	
Reliability Test	Conditions	Conditions		t# 1	Lot# 2	Lot# 3	
** Life Test	** Life Test 150C (408 Hrs)			7/0	77/0	77/0	
**High Temp Storage Bake	175C (500 Hrs)			8/0	80/0	79/0	
**Autoclave 121C (240 Hrs)			7/0	87/0	87/0		
**Biased HAST 130C/85%RH (96 Hrs)			7/0	77/0	77/0		
**Temperature Cycle -65C/+150C			77/0		77/0	77/0	
Surface Mount Solderability	Pb Free/Solder-		15/0		15/0	-	
Manufacturability (Assembly	) (per mfg. Site specif	(per mfg. Site specification)			Pass	Pass	
Moisture Sensitivity		(level 2 @ 260C peak +5/-0C)			12/0	12/0	
Notes **- Preconditioning	sequence: Level 2-2600	,					

# **Qualification Data: Group 2 Devices**

This qualification has been developed for the validation of this change. The qualification data validates that the proposed change meets the applicable released technical specifications.							
	Qual Vehicle 1: DRV91670PHPR (MSL 3-260C)						
Package Construction Details							
Assembly Site:	Mold Compou	nd:	4205	443			
# Pins-Designator, Family:	48-PHP, HTQFP	Mount Compou	nd:	4208	458		
Lead frame (Finish, Base):	NiPdAu, Cu	Bond Wi	ire: (	0.80	Mil Dia.,	Cu	
Qualification:  Plan  Test Results							
Reliability Test	Conditions		Sample Size/			'Fail	
Reliability Test	Conditions			# 1	Lot# 2	Lot# 3	
Electrical Characterization	-		Pass		Pass	Pass	
**High Temp Storage Bake	170C (420 Hrs)		77/0		77/0	77/0	
**Autoclave	121C (96 Hrs)			/0	77/0	77/0	
** Temperature Cycle	-65C/+150C (500 Cy	5C/+150C (500 Cyc)			77/0	77/0	
ESD CDM +/- 250V; +/- 1500V			3/0		ı	ı	
ESD HBM +/- 1000V; +/- 2500V			3/0		-	-	
Manufacturability (Assembly)	(per mfg. Site specification)			SS	Pass	Pass	
Moisture Sensitivity	(level 3 @ 260C peak +5/-0C)			/0	-	-	
Notes **- Preconditioning sequence: Level 3-260C.							

### Qualification Data: Group 3 Devices

Qualification Data: Group 3 Devices							
This qualification has been developed for the validation of this change. The qualification data							
validates that the proposed	change meets the applic	cable released technica	ıl spe	ecifica	tions.		
Qual Vehicle 1: SN74AHC1G126DBVR (MSL 1-260C)							
	Package Construction Details						
Assembly Site: HNT Mold Compound: 450413							
# Pins-Designator, Family: 5-DBV, SOT-23 Mount Compound: 400154							
Lead frame (Finish, Base): NiPdAu, Cu			re:	1.0 Mil Dia., Cu			
Qualification:  Plan  Test Results							
Deliability Teet	Sample Size/Fail						
Reliability Test	Conditions		Lot# 1		Lot# 2	Lot# 3	
**High Temp Storage Bake 170C (600 Hrs) 82/0 85/0 8				84/0			
**Autoclave	121C (192 Hrs)		77/0		77/0	77/0	
** Temperature Cycle	-65C/+150C (500 Cy	-65C/+150C (500 Cyc)		7/0	77/0	77/0	
Moisture Sensitivity	(level 1 @ 260C pea	(level 1 @ 260C peak +5/-0C)			22/0	22/0	
Notes **- Preconditioning	sequence: Level 1-2600	C.	•		•		

Qual V	ehicle 2 : SN74CBTLV	•	-26	OC)			
	Package Constr						
Assembly Site:	Mold Compour	nd:	450413				
# Pins-Designator, Family:	5-DBV, SOT-23	Mount Compour	nd:	4001	54		
Lead frame (Finish, Base):	NiPdAu, Cu	Bond Wi	re:	0.8 N	/lil Dia., C	u	
Qualification:	☐ Test Results						
Reliability Test	Conditions			Sar	nple Size	'Fail	
**High Temp Storage Bake	170C (600 Hrs)				90/0		
**Autoclave	121C (96 Hrs)				77/0		
**T/C -65C/150C	-65C/+150C (500 Cy	yc)			77/0		
Notes **- Preconditioning	sequence: Level 1-2600						
Qual '	Vehicle 3: SN74LVC1	GU04DBVR (MSL 1-2	260	C)			
	Package Constr	ruction Details					
Assembly Site:	HNT	Mold Compour	nd:	4504	13		
# Pins-Designator, Family:	5-DBV, SOT-23	Mount Compour	nd:	4001	54		
Lead frame (Finish, Base):	NiPdAu, Cu	Bond Wi	re:	0.80	Mil Dia.,	Cu	
Qualification:  Plan	☐ Test Results	<u> </u>					
Poliability Tost	Conditions		Samp		nple Size/	ple Size/Fail	
Reliability Test	Conditions	Conditions		t# 1	Lot# 2	Lot# 3	
**High Temp Storage Bake 170C (420 Hrs)			87/0		87/0	89/0	
**Autoclave		77/0		77/0	77/0		
**Biased HAST 130C/85%RH (192 H		Hrs)	8	0/0	80/0	80/0	
** Temperature Cycle	-65C/+150C (500 Cy	-65C/+150C (500 Cyc)			77/0	77/0	
Solderability	Pb Free/Solder			2/0	22/0	22/0	
Manufacturability (Assembly	(per mfg. Site specification)			ass	Pass	Pass	
Moisture Sensitivity	(level 1 @ 260C peak +5/-0C)			2/0	22/0	22/0	
Notes **- Preconditioning	sequence: Level 1-2600	D					
C	Qual Vehicle 4: TS321	11DBVT (MSL 1-2600	;)				
	Package Constr	ruction Details					
Assembly Site:	HNT	Mold Compour	nd:	4504	13		
# Pins-Designator, Family:	5-DBV, SOT-23	Mount Compour	nd:	4001	54		
		Bond Wi	ire: 1.0 Mil Dia., Cu				
Qualification:  Plan	☐ Test Results						
				Sar	nple Size/	'Fail	
Reliability Test	Conditions		Lot# 1		Lot# 2	Lot# 3	
**High Temp Storage Bake 170C (420 Hrs)			79/0		80/0	80/0	
**Autoclave	121C (192 Hrs)		77/0		77/0	77/0	
** Temperature Cycle	-65C/+150C (500 C)	vc)	77/0		77/0	77/0	
Moisture Sensitivity	(level 1 @ 260C pea		22/0		22/0	22/0	
					1		
Notes **- Preconditioning	sequence: Level 1-2600	C.					

Qual Vehicle 5: TS5A3166DBVR (MSL 1-260C)					
Package Construction Details					
Assembly Site:	HNT Mold Compound		nd:	450413	
# Pins-Designator, Family:	5-DBV, SOT-23	Mount Compound:		400154	
Lead frame (Finish, Base):	NiPdAu, Cu	Bond Wire:		0.8 Mil Dia., Cu	
Qualification:  Plan  Test Results					
Reliability Test	Conditions			Sample Size/Fail	
**Autoclave	121C (96 Hrs)	121C (96 Hrs)			
** Temperature Cycle	-65C/+150C (500 Cyc)			77/0	
Notes **- Preconditioning sequence: Level 1-260C.					

For questions regarding this notice, e-mails can be sent to the regional contacts shown below or your local Field Sales Representative.

Location	E-Mail
USA	PCNAmericasContact@list.ti.com
Europe	PCNEuropeContact@list.ti.com
Asia Pacific	PCNAsiaContact@list.ti.com
Japan	PCNJapanContact@list.ti.com